TOSHIBA Photocoupler IRED & Photo-Transistor

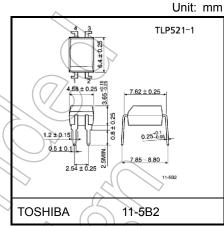
TLP521-1, TLP521-2, TLP521-4

Programmable Controllers AC/DC-Input Module Solid State Relay

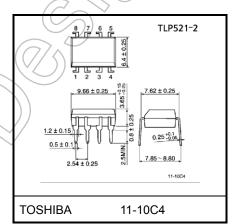
The TOSHIBA TLP521-1, -2 and -4 consist of a photo-transistor optically coupled to an infrared emitting diode.

The TLP521-2 offers two isolated channels in an eight lead plastic DIP package, while the TLP521-4 provides four isolated channels in a sixteen plastic DIP package.

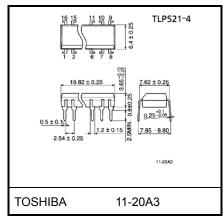
- Collector-emitter voltage: 55 V (min)
- Current transfer ratio: 50 % (min) Rank GB: 100 % (min)
- Isolation voltage: 2500 Vrms (min)
- UL-recognized: UL 1577, File No.E67349
- cUL-recognized: CSA Component Acceptance Service No.5A
 File No.E67349



Weight: 0.26 g (typ.)



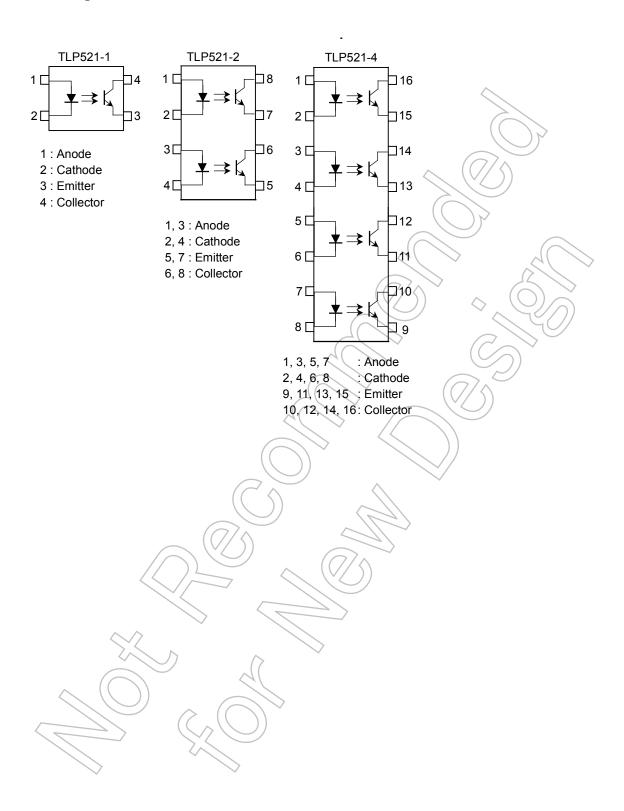
Weight: 0.54 g (typ.)



Weight: 1.1 g (typ.)

Start of commercial production 1979-05

Pin Configurations (top view)



Absolute Maximum Ratings (Ta = 25°C)

			Ra	ting	
	Characteristics	Symbol	TLP521-1	TLP521-2 TLP521-4	Unit
	Forward current	lF	70	50	mA
	Forward current derating	ΔI _F /°C	-0.93 (Ta ≥ 50°C)	-0.5 (Ta ≥ 25°C)	mA/°C
	Pulse forward current (100 µs pulse, 100 pps)	lFP	1 (A
LED	Reverse voltage	V_{R}		5	(
	Diode power dissipation	PD	150	100 (//	∕mW
	Diode power dissipation derating	ΔP _D /°C	-2.0 (Ta ≥ 50°C)	-1.0 (Ta ≥ 25°C)	mW/°C
	Junction temperature	Tj	12	°C	
	Collector-emitter voltage	VCEO	5	V	
	Emitter-collector voltage	V _{ECO}	-	V _((
j	Collector current	Ic	5	mÆ	
Detector	Collector power dissipation (1 circuit)	Pc	(A)	mW	
	Collector power dissipation derating (1 circuit) (Ta ≥ 25°C)	ΔP _C /°C	-1	.9	mW/°C
	Junction temperature	Tj	12	\bigcirc c	
Stor	rage temperature range	T _{stg}	-55 to	°C	
Оре	erating temperature range	Topr	-55 to	°C	
Lea	d soldering temperature (10 s)	T _{sol}	29	30	°C
Total package power dissipation (1 circuit)		Рт	250	150	mW
Total package power dissipation derating (1 circuit) (Ta ≥ 25°C)		ΔΡτ/°C	-2.5	-1.5	mW/°C
Isolation voltage (AC, 60 s, R.H.≤ 60 %) (Note 1)		BVs	25	00	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Device considered a two terminal device: LED side pins shorted together and detector side pins shorted together.

Recommended Operating Conditions

Characteristics	Symbol	Min	Тур.	Max	Unit
Supply voltage	Vcc	_	5	24	V
Forward current	lF	_	16	25	mA
Collector current	Ic	_	1	10	mA
Operating temperature	T _{opr}	-25	_	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Current transfer ratio

	Current Transfer Ratio (%) (Ic/IF)		Madring Of			
Туре	fication	IF = 5mA, VCE	= 5V, Ta = 25°C	Marking Of Classification		
	(Note 1)	Min	Max			
	Blank	50	600	Blank, Y [*] , YE, G, G [*] , GR, B, BL, GB		
	Rank Y	50	150	YE, Y■		
	Rank GR	100	300	GR, G, G		
	Rank BL	200	600	BL, B		
TLP521-1	Rank GB	100	600	GB, GR, G, G [*] , BL, B		
	Rank YH	75	150	Y*		
	Rank GRL	100	200	G		
	Rank GRH	150	300	G•		
	Rank BLL	200	600	В		
	Blank	50	600	Blank, GR, BL, GB		
TLP521-2	Rank GB	100	600	GB, GR, BL		
1LP521-2	Rank GR	100	300	GR		
	Rank BL	200	600	BL		
TLP521-4	Blank	50	600	Blank, GB		
114521-4	Rank GB	100	600	GB (7/4)		

Note 1: Ex. rank GB: TLP521-1 (GB)

Note: Application type name for certification test, please use standard product type name, i.e. TLP521-1 (GB): TLP521-1, TLP521-2 (GB): TLP521-2



Electrical Characteristics (Ta = 25°C)

	Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	VF	I _F = 10 mA	1.0	1.15	1.3	V
LED	Reverse current	I _R	V _R = 5 V	_	_	10	μA
	Capacitance	Ст	V = 0 V, f = 1 MHz	/	30	-	pF
	Collector-emitter breakdown voltage	V(BR)CEO	IC = 0.5 mA	55	_	_	V
۲	Emitter-collector breakdown voltage	V(BR)ECO	IE = 0.1 mA	\\Z_) —	_	V
Detector	Collector dark current ICEO	lono	V _{CE} = 24 V) }	10	100	nA
De	Collector dark current	ICEO	V _{CE} = 24 V, Ta = 85 °C))	2	50	μΑ
	Capacitance (collector to emitter)	C _{CE}	V = 0 V, f = 1 MHz		10		pF

Coupled Electrical Characteristics (Ta = 25°C)

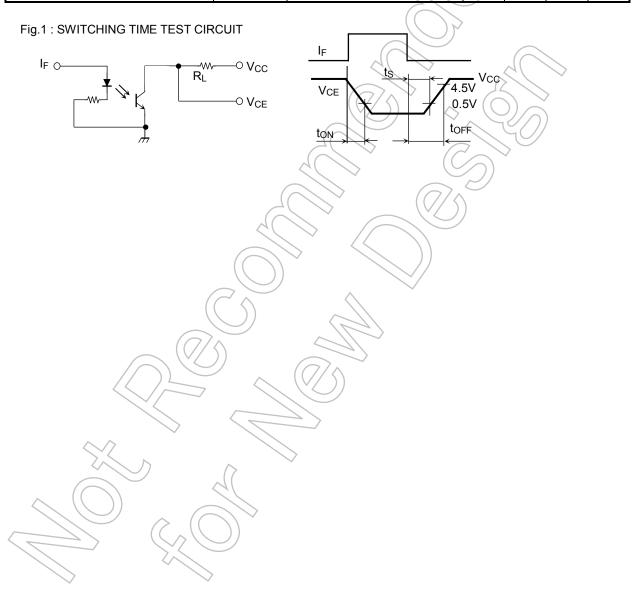
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Current transfer ratio	Ic/I _F	IF = 5 mA, VCE = 5 V	50	<u>U</u>	600	%
Carrent transfer rate	10/1	Rank GB	100	>	600	70
Saturated CTR	Io/Ic/+\	IF = 1 mA, VCE = 0.4 V	(γ)	60	_	%
Saturated CTR	IC/IF(sat)	30	_	_	/0	
		Ic = 2.4 mA, IF = 8 mA) —	_	0.4	
Collector-emitter saturation voltage	VCE(sat)	I _C = 0.2 mA, I _F = 1 mA	_	0.2	_	٧
-		Rank GB	_	_	0.4	

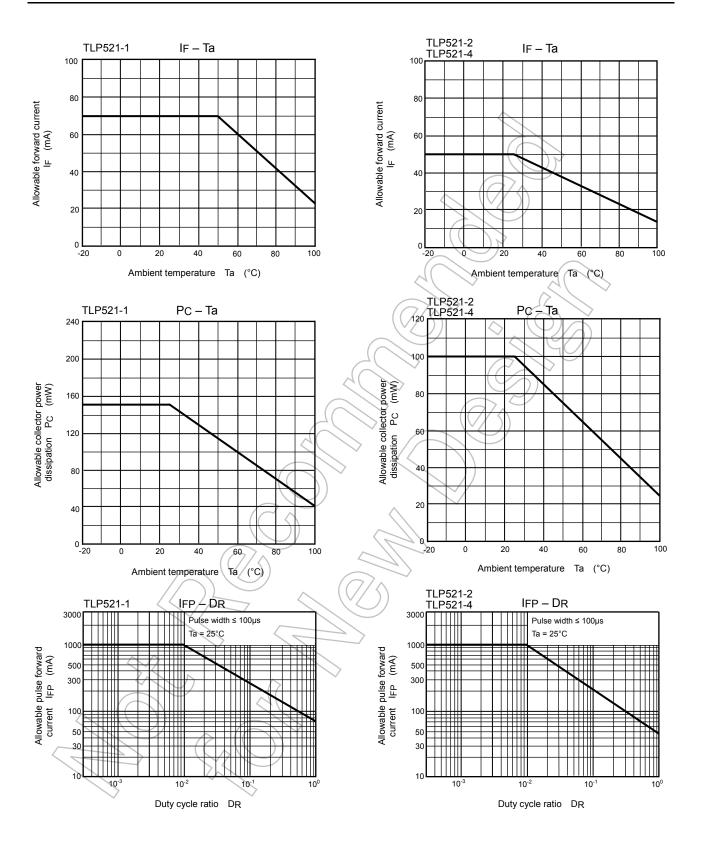
Isolation Characteristics (Ta = 25°C)

		110 31				
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance (input to output)	Cs	V _S = 0 V, f = 1 MHz	-	0.8	-	pF
Isolation resistance	Rs	V _S = 500 V, R.H.≤ 60 %	5×10 ¹⁰	10 ¹⁴	_	Ω
Isolation voltage	BVs	AC, 60 s	2500	_	_	Vrms

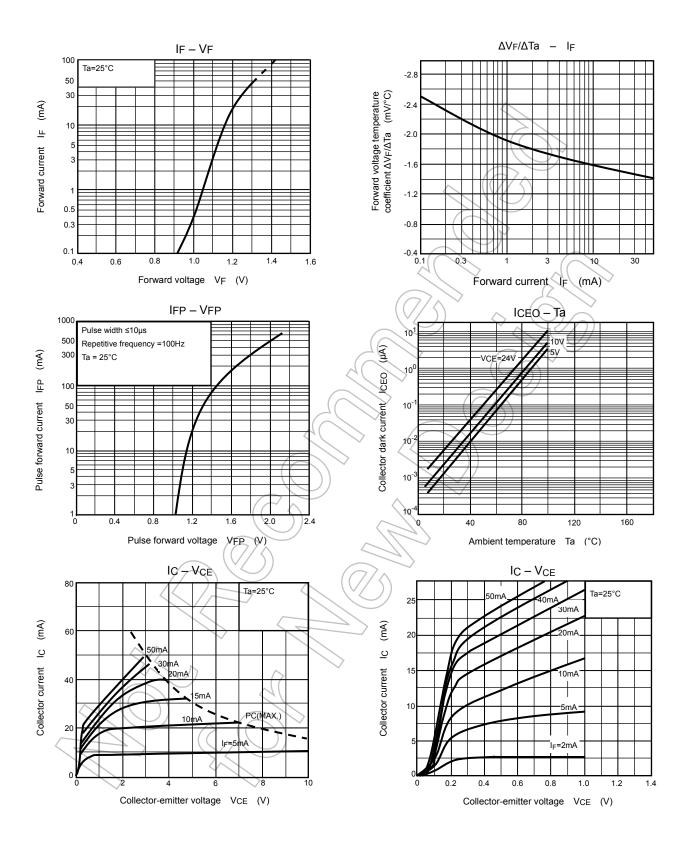
Switching Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Rise time	t _r		_	2	_	
Fall time	t _f	V _{CC} = 10 V	_	3	_	
Turn-on time	ton	$I_C = 2 \text{ mA}$ $R_L = 100 \Omega$	/-	3	_	μs
Turn-off time	toff			3	_	
Turn-on time	toN) 2	_	
Storage time	ts	$R_L = 1.9 \text{ k}\Omega$ (Fig.1) $V_{CC} = 5 \text{ V, I}_F = 16 \text{ mA}$) 	15	_	μs
Turn-off time	toff		$\supset \downarrow$	25	_	

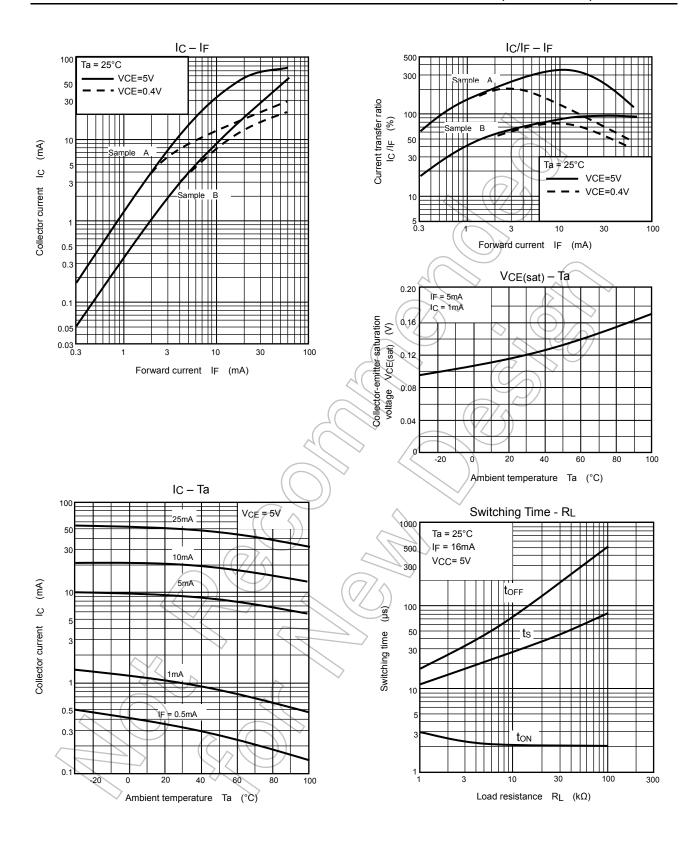




NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



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